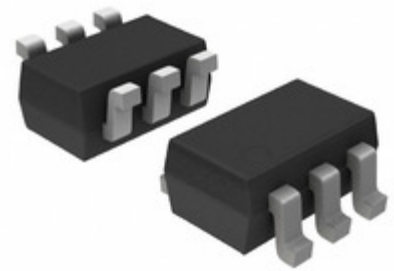









	<h2 style="color: #C00000;">MUN5313DW1T1G</h2>	
	Hersteller-Teilenummer:	MUN5313DW1T1G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN/PNP SOT363
Datenblätter:	 MUN5313DW1T1G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 2800 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	MUN5313DW1T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN/PNP SOT363
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	2800 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-88/SC70-6/SOT-363
Transistor-Typ	1 NPN, 1 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	47k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

MUN5313DW1T1G ist neu im Original, Suche MUN5313DW1T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie MUN5313DW1T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage MUN5313DW1T1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>MUN5312DW1T2G AMI Semiconductor / ON Semiconductor TRANS NPN/PNP PREBIAS SOT363</p>	 <p>MUN5312DW1T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT363</p>	 <p>MUN5315DW1T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT363</p>	 <p>MUN5315DW1T1 AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT363</p>
 <p>MUN5314DW1T1 ON ON SOT-363</p>	 <p>MUN5314DW1T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT363</p>	 <p>MUN5312DW1T1 ON ON SOT-363</p>	 <p>MUN5312DW1T2 ON MUN5312DW1T2 ON</p>

heiße Teile

Mehr

⊗ MUN2111LT1	↔ MUN2111T1	↔ MUN2111T1G	D MUN2112LT1G	↔ MUN2112T1
⊣ MUN2112T1G	⊗ MUN2113T1	D MUN2113T1G	↔ MUN2113XLT1	↔ MUN2114T1
⊗ MUN2114T1G	⊣ MUN2115T1	⊗ MUN2116T1	↔ MUN2116T1G	↔ MUN2132T1
D MUN2133T1	⊗ MUN2211T1	⊣ MUN2211T1B	⊗ MUN2211T1G	↔ MUN2211T1G/3G
↔ MUN2211T3G	↔ MUN2212LT1	⊗ MUN2212T1	⊣ MUN2212T1G	↔ MUN2213JT1
↔ MUN2213JT1G	↔ MUN2213T1	D MUN2213T1G	⊗ MUN2214T1G	⊣ MUN2215LT1
⊗ MUN2215LT1G	D MUN2215T1	↔ MUN2215T1G	↔ MUN2216T1	↔ MUN2216T1G
⊣ MUN2232T1G	⊗ MUN2233LT1G	↔ MUN2233RT1	↔ MUN2233T1G	↔ MUN2234T1G
⊗ MUN2237T1	⊣ MUN2237T1G	⊗ MUN5113T1G	D MUN5114T1G	↔ MUN5115DW1T1G
↔ MUN5213T1	⊗ MUN5215T1G	⊣ MUN5312DW1T2	⊗ PKF2611PI	↔ TPCF8305

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited